Weibing Wu

List of Publications by Year in descending order

Source: https://exaly.com/author-pdf/313777/publications.pdf

Version: 2024-02-01

23	549	13	23
papers	citations	h-index	g-index
23	23	23	857 citing authors
all docs	docs citations	times ranked	

#	Article	IF	CITATIONS
1	A comparative study of catalytic behaviors of Mn, Fe, Co, Ni, Cu and Zn–Based catalysts in steam reforming of methanol, acetic acid and acetone. International Journal of Hydrogen Energy, 2020, 45, 3815-3832.	7.1	78
2	A coaxial three-layer (Ni, Fe)O _x H _y /Ni/Cu mesh electrode: excellent oxygen evolution reaction activity for water electrolysis. Catalysis Science and Technology, 2020, 10, 1803-1808.	4.1	9
3	Oxidase-Inspired Selective 2e/4e Reduction of Oxygen on Electron-Deficient Cu. ACS Applied Materials & amp; Interfaces, 2020, 12, 4833-4842.	8.0	31
4	Alkaline electrolyte: toward high-quality CdTe films with the assistance of strong complexing agent and organic base. CrystEngComm, 2018, 20, 8-11.	2.6	4
5	Structural modulation of CdS/ZnO nanoheterojunction arrays for full solar water splitting and their related degradation mechanisms. Catalysis Science and Technology, 2018, 8, 5280-5287.	4.1	11
6	CdCl 2 -assisting heat-treatment: Enhanced photoelectrocatalytic hydrogen generation and stability of CdS/ZnO nanoheterojunction arrays. International Journal of Hydrogen Energy, 2018, 43, 9969-9977.	7.1	15
7	Improved photocatalytic efficiency and stability of CdS/ZnO shell/core nanoarrays with high coverage and enhanced interface combination. International Journal of Hydrogen Energy, 2017, 42, 848-857.	7.1	25
8	Structure and property of CdS thin films with different residual chlorine content. Materials Research Express, 2016, 3, 106404.	1.6	2
9	Resistive switching behavior of Sb2S3 thin film prepared by chemical bath deposition. Materials Science in Semiconductor Processing, 2016, 44, 18-22.	4.0	7
10	Electrodeposition of wurtzite CdTe and the potential dependence of the phase structure. Materials Letters, 2016, 166, 85-88.	2.6	16
11	Orientational growth and resistive switching behavior of anatase TiO2 thin films. Materials Chemistry and Physics, 2015, 156, 76-81.	4.0	6
12	Continuous growth and improved PL property of ZnO nanoarrays with assistance of polyethylenimine. Nanoscale, 2013, 5, 5986.	5.6	52
13	Orientation growth and electrical property of CuSCN films associated with the surface states. CrystEngComm, 2012, 14, 6750.	2.6	20
14	Statistical mechanical origin of hysteresis in ferroelectrics. Journal of Applied Physics, 2012, 112, 034113.	2.5	4
15	Comparative study on aging effect in BiFeO3 thin films substituted at A- and B-sites. Applied Physics Letters, 2011, 99, .	3.3	33
16	Large Piezoelectric Coefficient in Tbâ€Doped BiFeO ₃ Films. Journal of the American Ceramic Society, 2010, 93, 948-950.	3.8	46
17	Thickness effects of Bi3.5Nd0.5Ti3O12 buffer layers on structure and electrical properties of BiFeO3 films. Journal of Materials Science, 2009, 44, 3556-3560.	3.7	3
18	Preparation and ferroelectric properties of predominantly (100)-oriented SrBi4Ti4O15 ferroelectric thin film on Pt(111)/TiO2/SiO2/Si(100) substrate. Journal of Materials Science: Materials in Electronics, 2009, 20, 113-116.	2.2	2

WEIBING Wu

#	Article	lF	CITATION
19	Agingâ€Induced Double Ferroelectric Hysteresis Loops and Asymmetric Coercivity in Asâ€Deposited BiFe _{0.95} Zn _{0.05} O ₃ Thin Film. Journal of the American Ceramic Society, 2009, 92, 1610-1612.	3.8	28
20	Lowâ€Temperature Fabrication and Enhanced Ferro―and Piezoelectric Properties of Bi _{3.7} Nd _{0.3} Ti ₃ O ₁₂ Films on Indium TinOxide/Glass Substrates. Journal of the American Ceramic Society, 2009, 92, 1556-1559.	3.8	15
21	Preparation and ferroelectric properties of (124)-oriented SrBi4Ti4O15 ferroelectric thin film on (110)-oriented LaNiO3 electrode. Journal of Materials Science: Materials in Electronics, 2008, 19, 1031-1034.	2.2	6
22	Epitaxy of Vertical ZnO Nanorod Arrays on Highly (001)-Oriented ZnO Seed Monolayer by a Hydrothermal Route. Crystal Growth and Design, 2008, 8, 4014-4020.	3.0	115
23	Enhanced ferroelectric properties of predominantly (100)-oriented CaBi4Ti4O15 thin films on Ptâ^•Tiâ^•SiO2â^•Si substrates. Journal of Applied Physics, 2008, 103, 056109.	2.5	21